

TOSHIBA Transistor Silicon NPN Epitaxial Planar Type

# 2SC5087

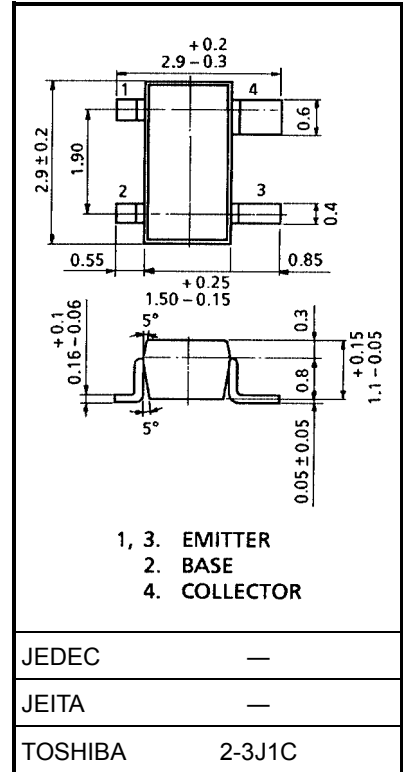
## VHF~UHF Band Low Noise Amplifier Applications

Unit: mm

- Low noise figure, high gain.
- $NF = 1.1\text{dB}$ ,  $|S_{21e}|^2 = 13\text{dB}$  ( $f = 1\text{GHz}$ )

### Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

| Characteristics             | Symbol    | Rating  | Unit             |
|-----------------------------|-----------|---------|------------------|
| Collector-base voltage      | $V_{CBO}$ | 20      | V                |
| Collector-emitter voltage   | $V_{CEO}$ | 12      | V                |
| Emitter-base voltage        | $V_{EBO}$ | 3       | V                |
| Base current                | $I_B$     | 40      | mA               |
| Collector current           | $I_C$     | 80      | mA               |
| Collector power dissipation | $P_C$     | 150     | mW               |
| Junction temperature        | $T_j$     | 125     | $^\circ\text{C}$ |
| Storage temperature range   | $T_{stg}$ | -55~125 | $^\circ\text{C}$ |



### Microwave Characteristics ( $T_a = 25^\circ\text{C}$ )

Weight: 0.012 g (typ.)

| Characteristics      | Symbol            | Test Condition  | Min | Typ. | Max | Unit |
|----------------------|-------------------|---|-----|------|-----|------|
| Transition frequency | $f_T$             | $V_{CE} = 10\text{V}$ , $I_C = 20\text{mA}$                       | 5   | 7    | —   | GHz  |
| Insertion gain       | $ S_{21e} ^2 (1)$ | $V_{CE} = 10\text{V}$ , $I_C = 20\text{mA}$ , $f = 500\text{MHz}$ | —   | 18   | —   | dB   |
|                      | $ S_{21e} ^2 (2)$ | $V_{CE} = 10\text{V}$ , $I_C = 20\text{mA}$ , $f = 1\text{GHz}$   | 9.5 | 13   | —   |      |
| Noise figure         | NF (1)            | $V_{CE} = 10\text{V}$ , $I_C = 5\text{mA}$ , $f = 500\text{MHz}$  | —   | 1    | —   | dB   |
|                      | NF (2)            | $V_{CE} = 10\text{V}$ , $I_C = 5\text{mA}$ , $f = 2\text{GHz}$    | —   | 1.1  | 2   |      |

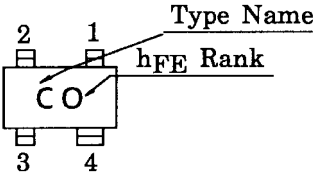
### Electrical Characteristics ( $T_a = 25^\circ\text{C}$ )

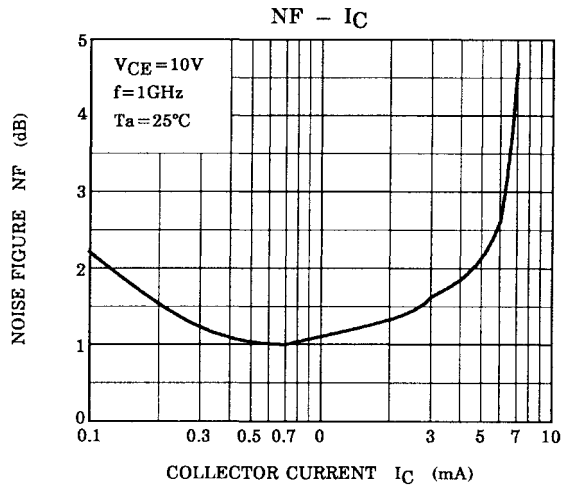
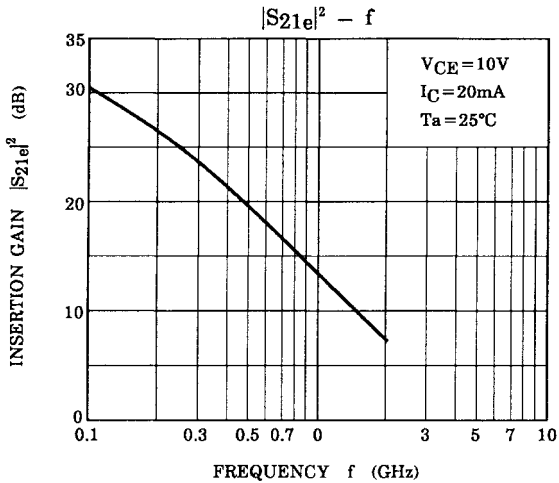
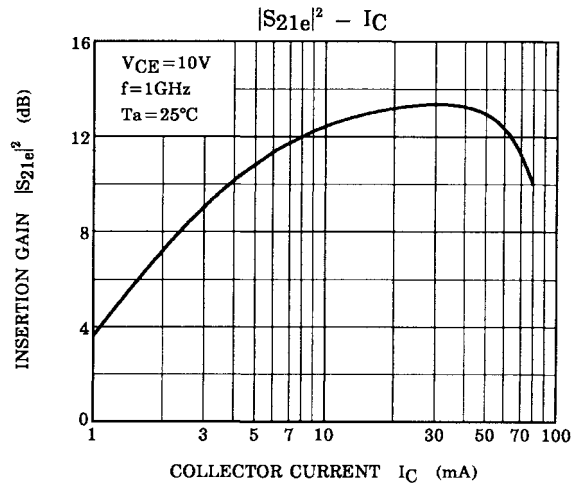
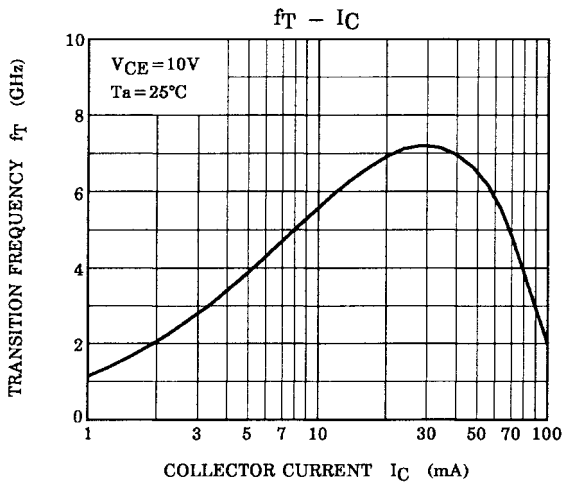
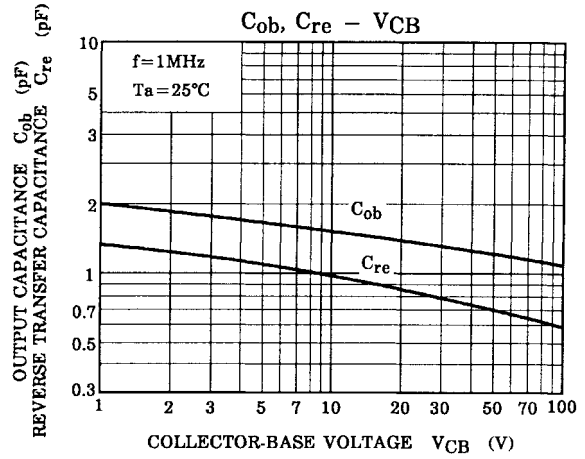
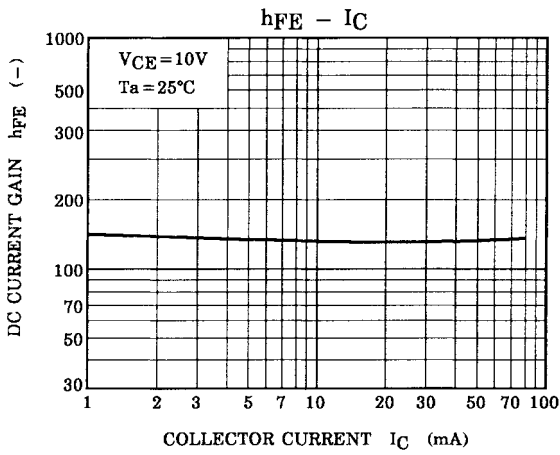
| Characteristics              | Symbol               | Test Condition   | Min | Typ. | Max  | Unit          |
|------------------------------|----------------------|--|-----|------|------|---------------|
| Collector cut-off current    | $I_{CBO}$            | $V_{CB} = 10\text{V}$ , $I_E = 0$                              | —   | —    | 1    | $\mu\text{A}$ |
| Emitter cut-off current      | $I_{EBO}$            | $V_{EB} = 1\text{V}$ , $I_C = 0$                               | —   | —    | 1    | $\mu\text{A}$ |
| DC current gain              | $h_{FE}$<br>(Note 1) | $V_{CE} = 10\text{V}$ , $I_C = 20\text{mA}$                    | 80  | —    | 240  |               |
| Output capacitance           | $C_{ob}$             | $V_{CB} = 10\text{V}$ , $I_E = 0$ , $f = 1\text{MHz}$ (Note 2) | —   | 1.1  | 1.6  | pF            |
| Reverse transfer capacitance | $C_{re}$             |  | —   | 0.65 | 1.05 | pF            |

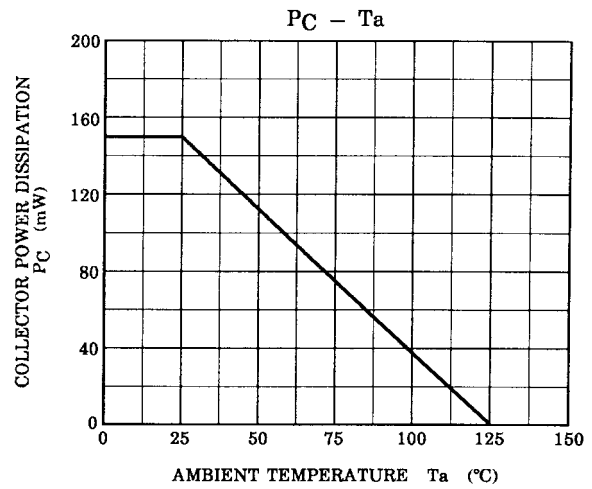
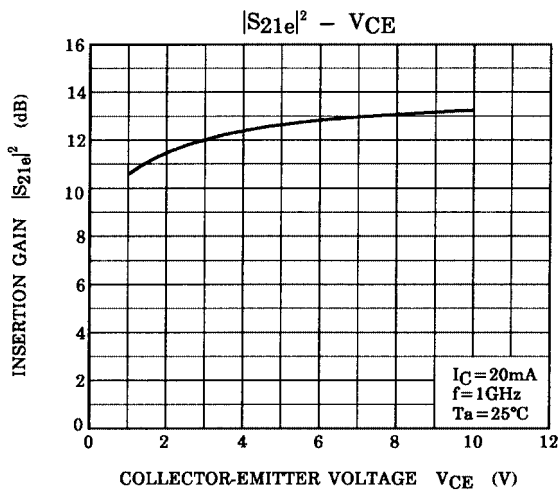
Note 1:  $h_{FE}$  classification O: 80~160, Y: 120~240

Note 2:  $C_{re}$  is measured by 3 terminal method with capacitance bridge.

**Marking**







## S-Parameter $Z_O = 50 \Omega$ , $T_a = 25^\circ\text{C}$

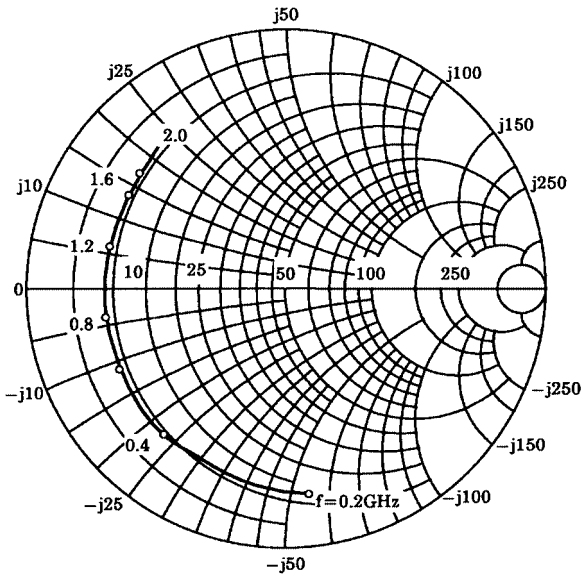
$V_{CE} = 10 \text{ V}$ ,  $I_C = 5 \text{ mA}$

| Frequency<br>MHz | S11   |        | S21    |       | S12   |      | S22   |        |
|------------------|-------|--------|--------|-------|-------|------|-------|--------|
|                  | Mag.  | Ang.   | Mag.   | Ang.  | Mag.  | Ang. | Mag.  | Ang.   |
| 200              | 0.793 | -82.4  | 11.923 | 133.4 | 0.050 | 52.7 | 0.788 | -36.4  |
| 400              | 0.736 | -128.0 | 7.835  | 108.5 | 0.066 | 38.0 | 0.584 | -53.4  |
| 600              | 0.719 | -152.1 | 5.578  | 94.5  | 0.071 | 34.1 | 0.490 | -63.5  |
| 800              | 0.701 | -168.6 | 4.279  | 84.4  | 0.073 | 33.9 | 0.445 | -72.2  |
| 1000             | 0.698 | 178.9  | 3.451  | 76.6  | 0.074 | 36.7 | 0.424 | -80.5  |
| 1200             | 0.697 | 168.3  | 2.855  | 69.9  | 0.076 | 40.8 | 0.413 | -88.9  |
| 1400             | 0.699 | 159.4  | 2.440  | 64.0  | 0.078 | 46.6 | 0.404 | -97.3  |
| 1600             | 0.703 | 150.8  | 2.121  | 59.3  | 0.084 | 52.5 | 0.401 | -105.4 |
| 1800             | 0.713 | 142.9  | 1.876  | 54.5  | 0.091 | 58.3 | 0.398 | -112.6 |
| 2000             | 0.722 | 134.7  | 1.681  | 50.3  | 0.100 | 63.5 | 0.398 | -119.6 |

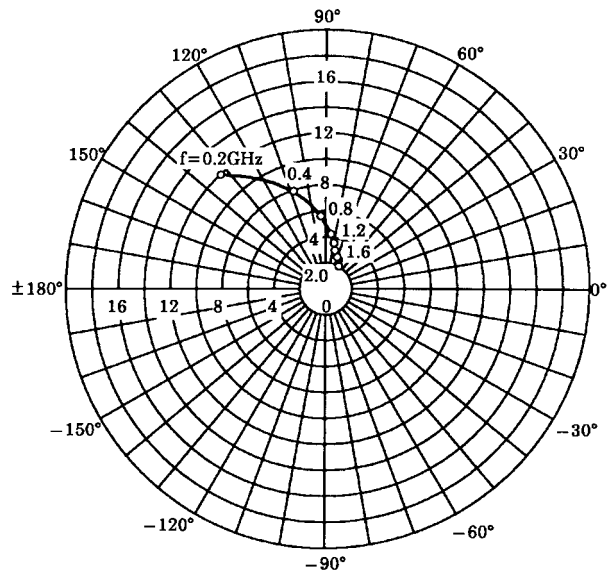
$V_{CE} = 10 \text{ V}$ ,  $I_C = 20 \text{ mA}$

| Frequency<br>MHz | S11   |        | S21    |       | S12   |      | S22   |        |
|------------------|-------|--------|--------|-------|-------|------|-------|--------|
|                  | Mag.  | Ang.   | Mag.   | Ang.  | Mag.  | Ang. | Mag.  | Ang.   |
| 200              | 0.655 | -129.4 | 20.724 | 113.2 | 0.031 | 48.0 | 0.496 | -59.6  |
| 400              | 0.650 | -161.5 | 11.288 | 95.5  | 0.040 | 50.4 | 0.319 | -74.1  |
| 600              | 0.660 | -176.3 | 7.643  | 86.4  | 0.049 | 56.4 | 0.263 | -83.5  |
| 800              | 0.666 | 172.8  | 5.758  | 79.6  | 0.059 | 60.0 | 0.242 | -92.9  |
| 1000             | 0.667 | 164.0  | 4.605  | 74.2  | 0.070 | 63.6 | 0.233 | -102.0 |
| 1200             | 0.668 | 156.8  | 3.809  | 69.3  | 0.080 | 65.9 | 0.229 | -111.0 |
| 1400             | 0.677 | 148.4  | 3.277  | 65.1  | 0.091 | 68.2 | 0.226 | -119.1 |
| 1600             | 0.676 | 141.1  | 2.862  | 61.2  | 0.104 | 70.0 | 0.223 | -126.5 |
| 1800             | 0.688 | 133.9  | 2.559  | 57.5  | 0.117 | 71.2 | 0.220 | -132.4 |
| 2000             | 0.690 | 126.7  | 2.303  | 54.1  | 0.131 | 72.4 | 0.217 | -137.8 |

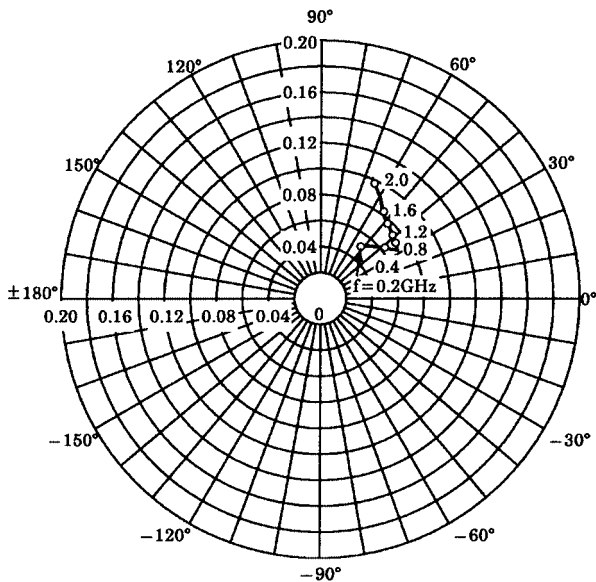
$S_{11e}$   
 $V_{CE} = 10V$   
 $I_C = 5mA$   
 $T_a = 25^\circ C$   
 (Unit :  $\Omega$ )



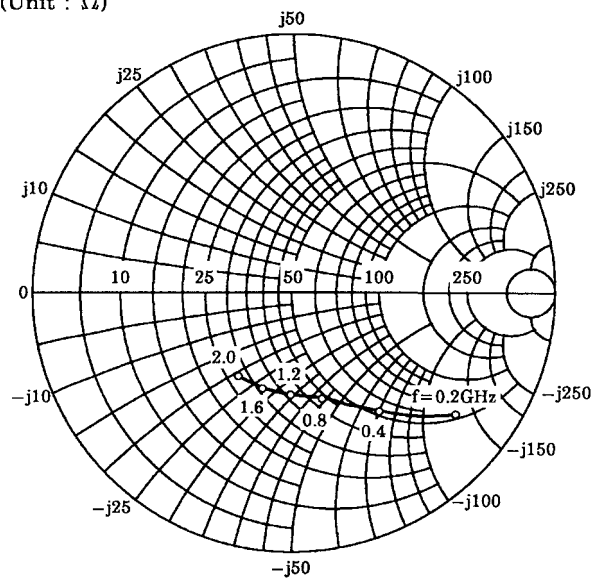
$S_{21e}$   
 $V_{CE} = 10V$   
 $I_C = 5mA$   
 $T_a = 25^\circ C$



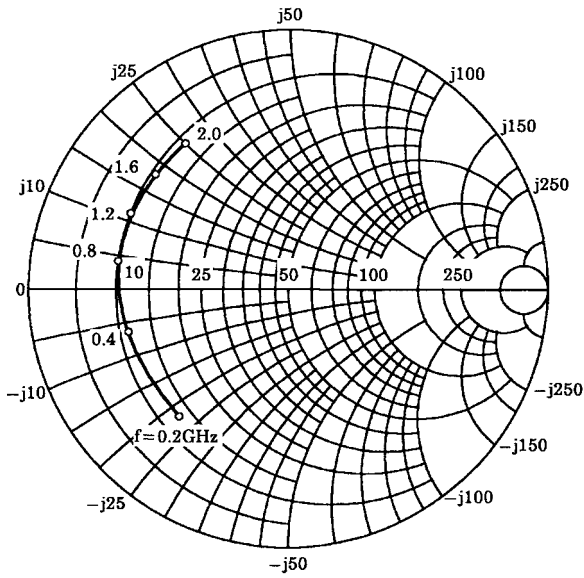
$S_{12e}$   
 $V_{CE} = 10V$   
 $I_C = 5mA$   
 $T_a = 25^\circ C$



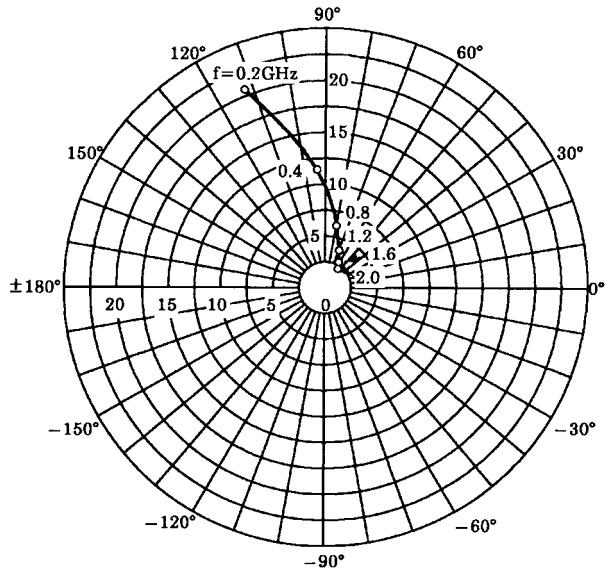
$S_{22e}$   
 $V_{CE} = 10V$   
 $I_C = 5mA$   
 $T_a = 25^\circ C$   
 (Unit :  $\Omega$ )



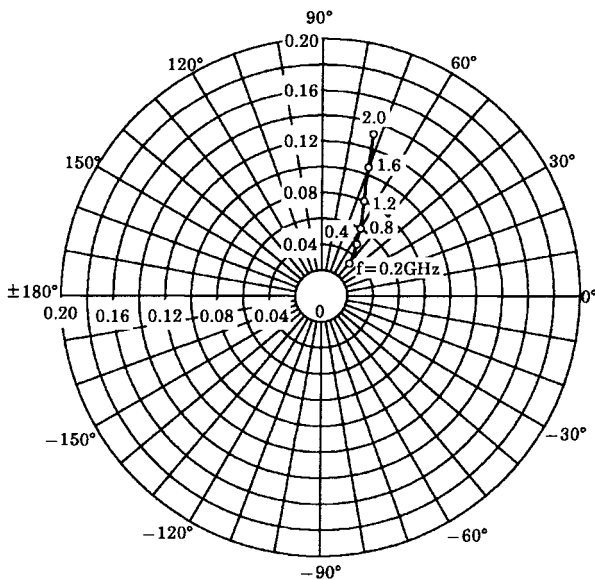
**S11e**  
 VCE = 10V  
 IC = 20mA  
 Ta = 25°C  
 (Unit : Ω)



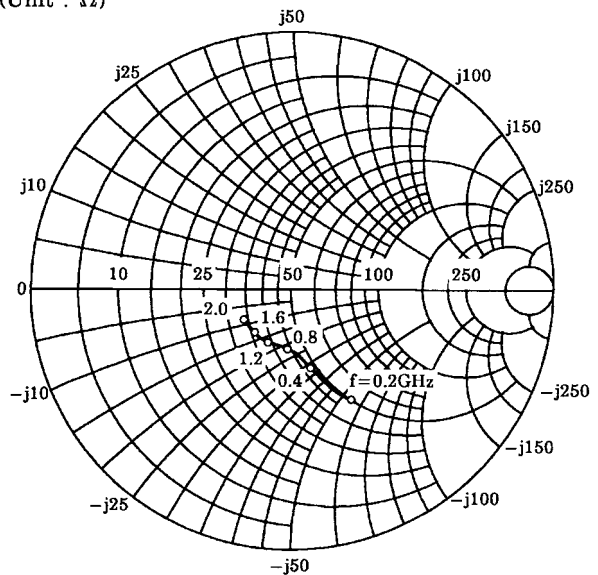
**S21e**  
 VCE = 10V  
 IC = 20mA  
 Ta = 25°C



**S12e**  
 VCE = 10V  
 IC = 20mA  
 Ta = 25°C



**S22e**  
 VCE = 10V  
 IC = 20mA  
 Ta = 25°C  
 (Unit : Ω)



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